

SEMICONDUCTOR®

KSC388

TV Final Picture IF Amplifier Applications

- G_{PE}= 33dB (TYP) at f=45MHz
 Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



NPN Epitaxial Silicon Transistor

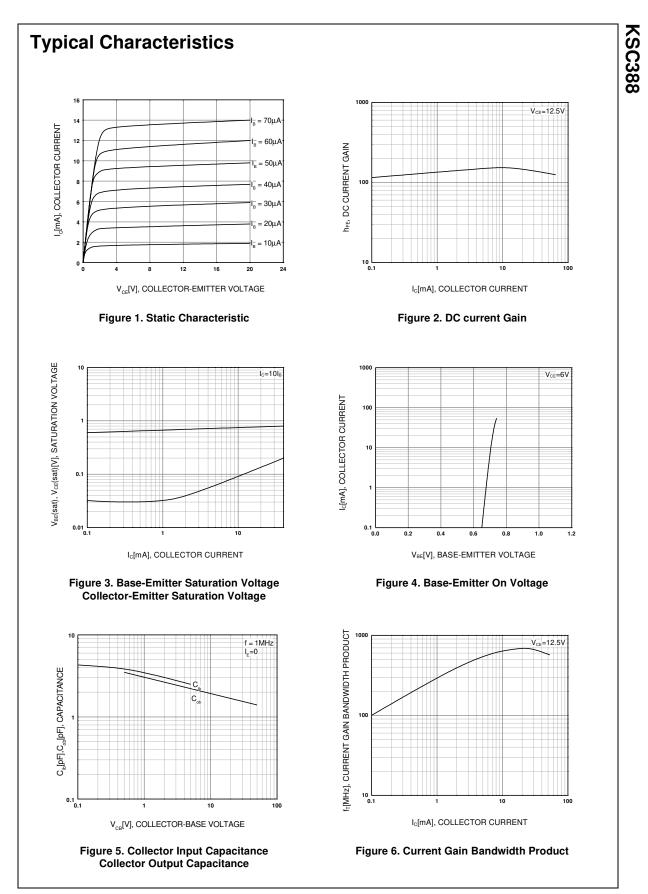
Absolute Maximum	Ratings	T _a =25°C unless otherwise noted
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Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	30	V	
V _{CEO}	Collector-Emitter Voltage	25	V	
V _{EBO}	Emitter-Base Voltage	4	V	
I _C	Collector Current	50	mA	
P _C	Collector Power Dissipation	300	mW	
ТJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	-55 ~ 150	°C	

Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

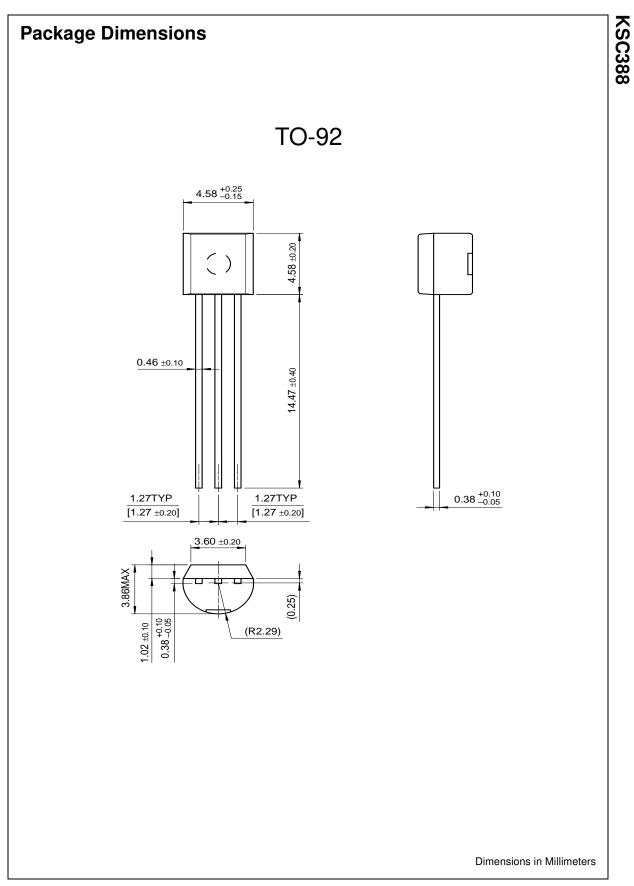
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μA, I _E =0	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	25			V
I _{CBO}	Collector Cut-off Current	V _{CB} =30V, I _E =0			0.1	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} =3V, I _C =0			0.1	μA
h _{FE}	DC Current Gain	V _{CE} =12.5V, I _C =12.5mA	20		200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =15mA, I _B =1.5mA			0.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =15mA, I _B =1.5mA			1.5	V
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz	0.8		2	pF
C _{c·rbb} ′	Collector-Base Time Constant	V _{CB} =10V, I _C =1mA f=30MHz			25	ps
f _T	Current Gain Bandwidth Product	V _{CE} =12.5V, I _C =12.5mA	300			MHz
G _{PE}	Power Gain	V _{CC} =12.5V, I _C =12.5mA f=45MHz	28	33	36	dB

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